## NSN 5962-01-374-2550

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-374-2550
Body Length:
Between 0.140 inches and 1.060 inches
Body Width:
Between 0.290 inches and 0.310 inches
Body Height:
Between 0.180 inches and 0.200 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Eolorops
Features Provided:
Bipolar and electrostatic sensitive and monolithic and programmed and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed
Voltage Rating And Type Per Characteristic:
0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Special Features:

Esd; altered item using 5962-8515517rx; filename; 1059 u55.Jed, media drawing; fd137200030-001; checksum "459e"

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

20 printed circuit

## NSN 5962-01-374-2550

Memory Microcircuit - Page 2 of 2



Sı	oec	ific	cati	on	Data:

67268-5962-85155 government standard

Shelf Life:

N/a

**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0